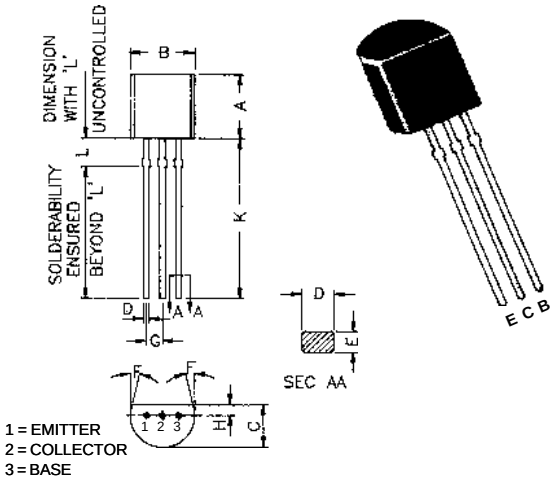
TO-92 Plastic Package **CSA733**

PNP SILICON PLANAR EPITAXIAL TRANSISTOR

Low Frequency Amplifier
Complementary to CSC945



DIM	MIN	MAX
A	4,32	5,33
B	4,45	5,20
C	3,18	4,19
D	0,41	0,55
E	0,35	0,50
F	5 DEG	
G	1,14	1,40
H	1,14	1,53
K	12,70	–
L	1.982	2.082

ALL DIMENSIONS IN M.M.

ABSOLUTE MAXIMUM RATINGS

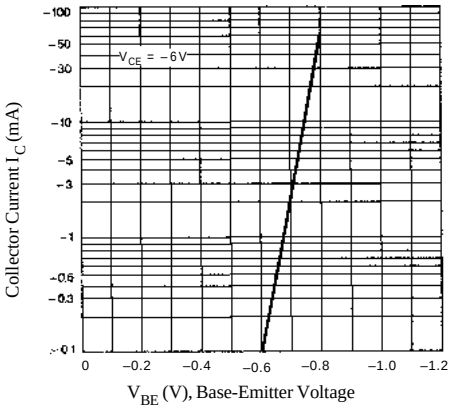
Rating	*Symbol*	*Value*	*Unit*
Collector-Base Voltage	BV_{CBO}	*60*	*V*
Collector-Emitter Voltage	BV_{CEO}	*50*	*V*
Emitter Base Voltage	BV_{EBO}	*5*	*V*
Collector Current (DC)	I_C	*100*	*mA*
Base Current (DC)	I_B	*20*	*mA*
Total Power Dissipation @ T_{amb} = 25 °C	P_{tot}	*500*	*mW*
Operating Storage Junction Temperature Range	T_j, T_{stg}	*-55 to +150*	*°C*

ELECTRICAL CHARACTERISTICS *(Ta=25 °C unless otherwise specified)*

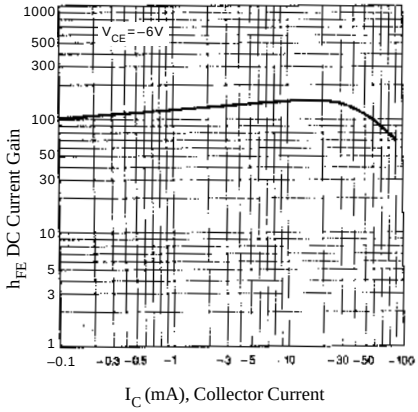
Characteristic	*Symbol*	*Min*	*Typ*	*Max*	*Unit*
Collector Emitter Breakdown Voltage					
I_C=1mA, I_B=0	BV_{CEO}	50	-	-	V
Collector Base Voltage					
I_C=100μA, I_E=0	BV_{CBO}	60	-	-	V
Emitter Base Voltage					
I_E=10μA, I_C=0	BV_{EBO}	5	-	-	V
Collector Cut-Off Current					
V_{CB}=60V, I_E=0	I_{CBO}	-	-	0.1	μA
Emitter Cut-Off Current					
V_{EB}=5V, I_C=0	I_{EBO}	-	-	0.1	μA
DC Current Gain					
V_{CE}=6V, I_C=1mA	h_{FE*}	90	-	600	
Collector Emitter Saturation Voltage					
I_C=100mA, I_B=10mA	$V_{CE(sat)}$	-	-	0.3	V
Base Emitter On Voltage					
I_C=1mA, V_{CE}=6V	$V_{BE(on)}$	0.6	-	0.7	V
DYNAMIC CHARACTERISTICS					
Current-Gain Bandwidth Product					
V_{CE}=6V, I_C=10mA	f_T	100	-	-	MHz
Common Base Output Capacitance					
V_{CB}=10V, I_E=0, f=1MHz	C_{ob}	-	-	6	pF
Noise Figure					
V_{CE}=6V, I_C=0.3mA	NF	-	-	20	dB
R_s=10kΩ, f=100Hz					

h_{FE} CLASSIFICATION	***R***	***Q***	***P***	***K***
	90-180	***135=270***	***200-400***	***300-600***

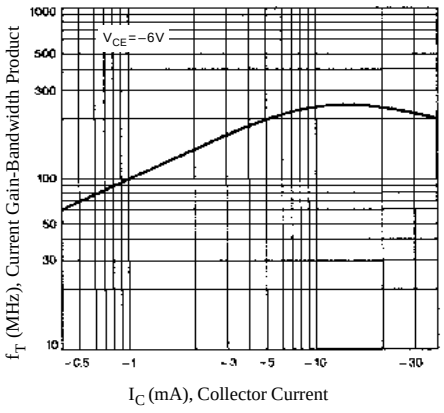
Base Emitter On Voltage



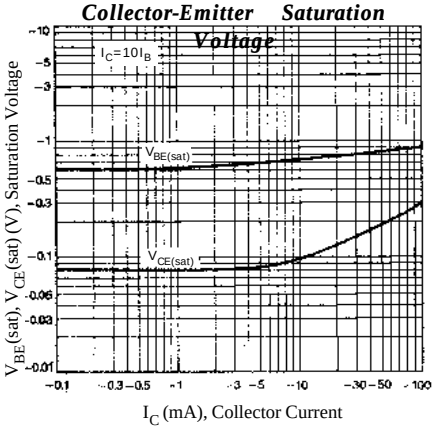
DC Current Gain



Current Gain-Bandwidth Product



Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage



Customer Notes

Disclaimer

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